

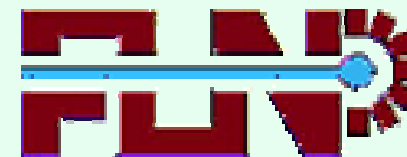
Formation and ripening of antiferromagnetic domains in a Fe/Cr multilayer

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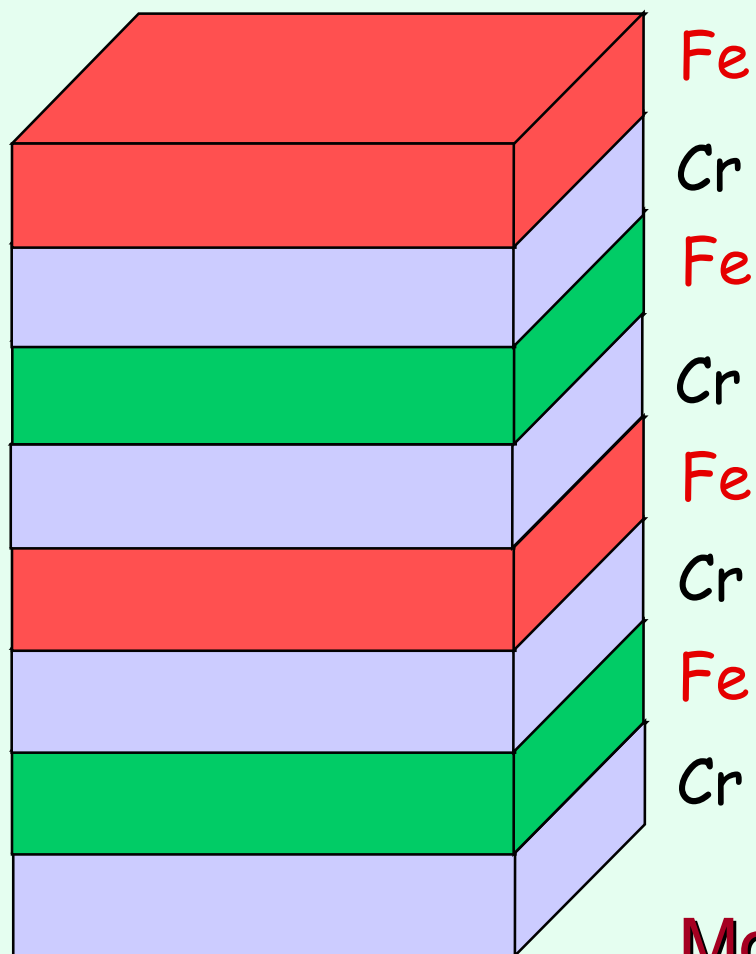


Outline

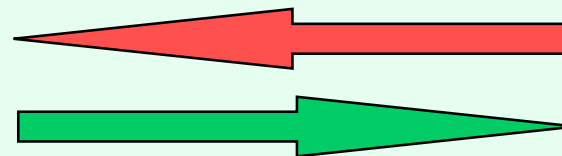
- Introduction: coupled multilayers, magnetic and domain structure, reflectometry
- Native patch-domain formation in antiferromagnetically coupled multilayers
- Spontaneous and irreversible growth of the domain size in decreasing field: the domain ripening

AF coupled multilayers
and patch domains

Antiferromagnetically coupled Fe/Cr multilayer



Layer magnetisations:

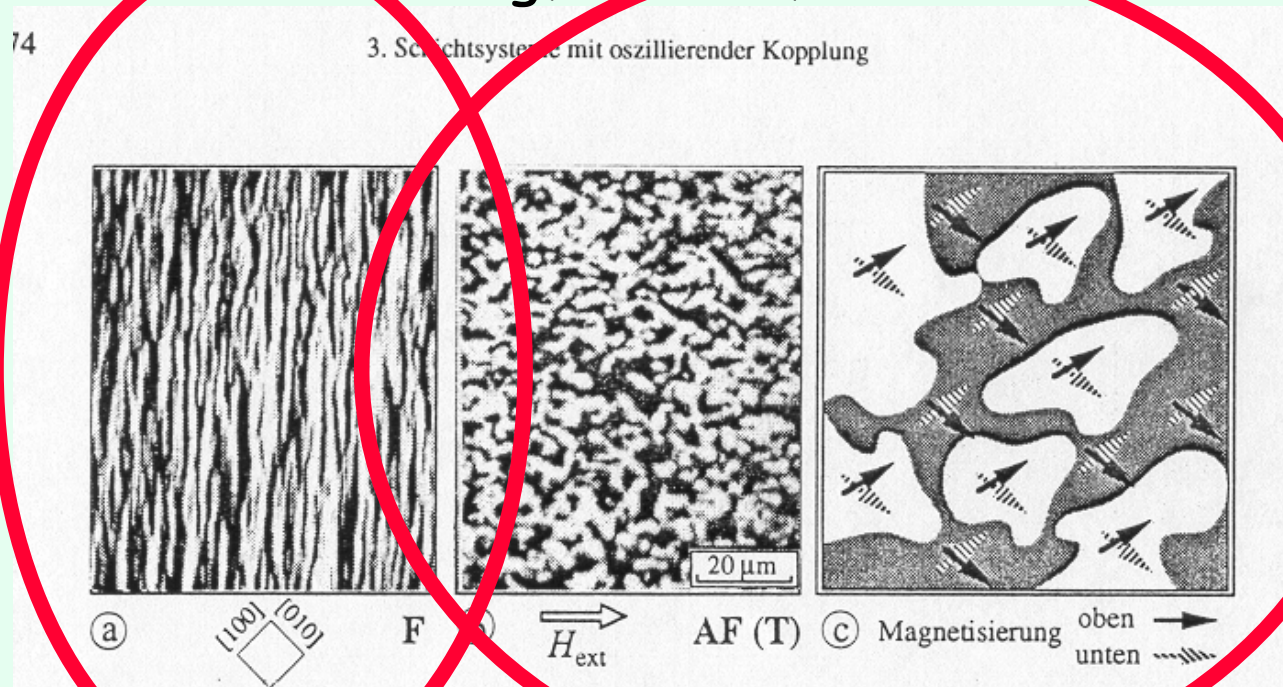


$\text{MgO}(001)[^{57}\text{Fe}(26\text{\AA})/\text{Cr}(13\text{\AA})]_{20}$

Domains in a Fe/Cr/Fe trilayer

M. Rührig et al., Phys. Stat. Sol. (a) 125, 635 (1991).

M. Rührig, Theses, 1993.

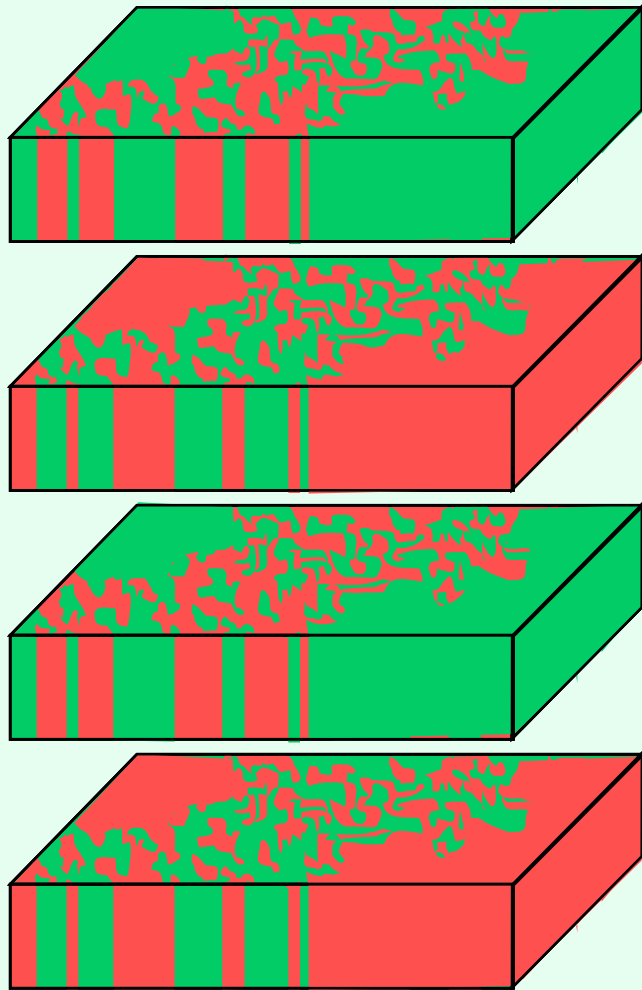


'Ripple'
domains

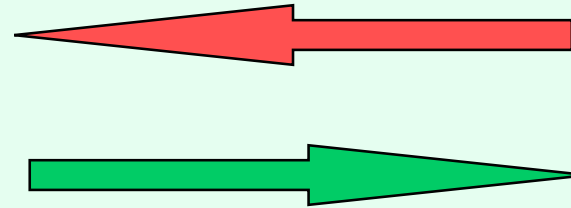
'Patch'
domains

Abb. 3.5 Domänenkeimbildung in ferromagnetisch- und antiferromagnetisch gekoppelten Zonen der einkristallinen Keilproben aus der Sättigung in schwerer Richtung kommend. Für F-gekoppelte Bereiche findet man wie in Einfachschichten eine ausgeprägte *Ripplebildung*, die in Remanenz zu einem stark anisotropen Domänenmuster führt (a). Im AF-Gebiet dagegen beobachtet man ein isotropes fleckenartiges Keimbildungsmuster (b), da dort die bevorzugte Antiparallelstellung der Magnetisierung der beiden Schichten eine Kompensation der transversalen Komponente der Magnetisierung bewirkt (c). Das Fleckenmuster wird auch in den Übergangszonen gefunden (s. unten). (a) und (b) aus [3.9])

Patch domains in AF-coupled multilayers



Layer magnetisations:

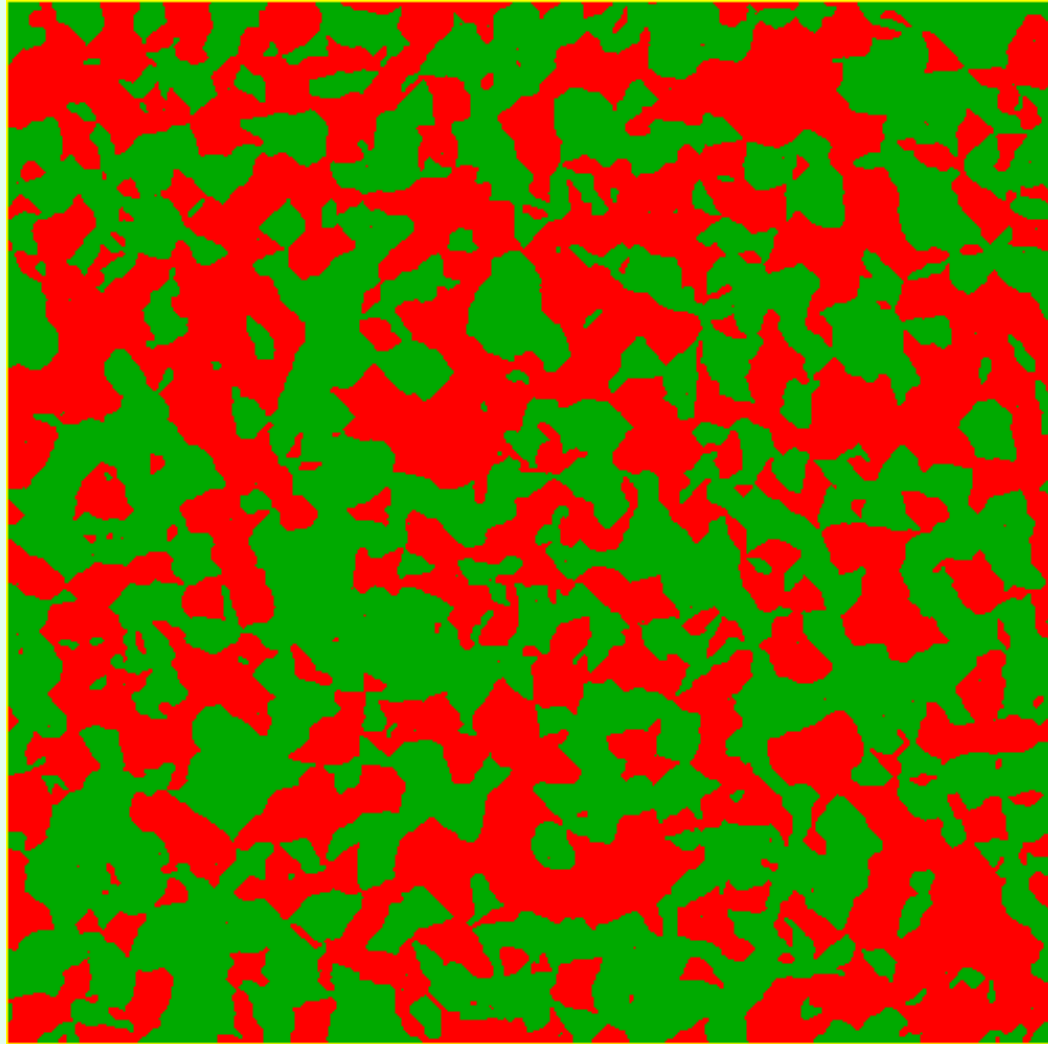


The 'magnetic field lines' are shortcut by the AF structure → the stray field is reduced → no 'ripple' but 'patch' domains are formed.

The patch domains

- The domain-size-dependent magnetoresistance noise may be as high as to **limit GMR applications** → 'tailoring' of the domain structure ('**domain engineering**') is required.
- The first step towards domain engineering is to understand **the formation mechanism of patch domains**.

Domain formation on leaving saturation




From saturation to remanence: the domain ripening


- The domain structure in **remanence** may differ from that of the **native domains**.
- The **domain-wall energy** is increasing in decreasing field.
- In order to decrease the **surface density of the domain-wall energy**, the multilayer spontaneously **increases the average size** of the patch domains ('ripening').
- The spontaneous domain growth is **limited** by domain-wall pinning (**coercivity**).

Polarized Neutron Reflectometry (PNR)

Neutron reflectometry: the scattering amplitudes

$$f_n = f_n^{\text{nuc}} + f_n^{\text{mag}}$$


isotope-specific
scattering length

$$f_n^{\text{mag}} = \pm b$$


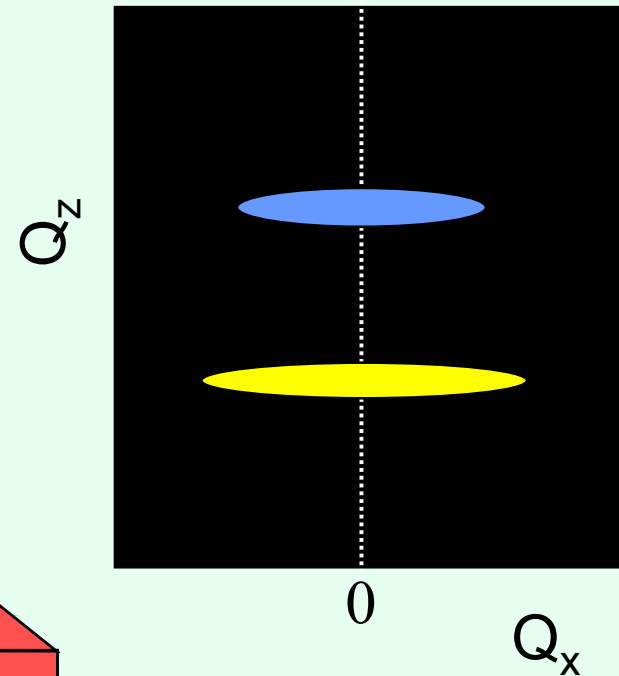
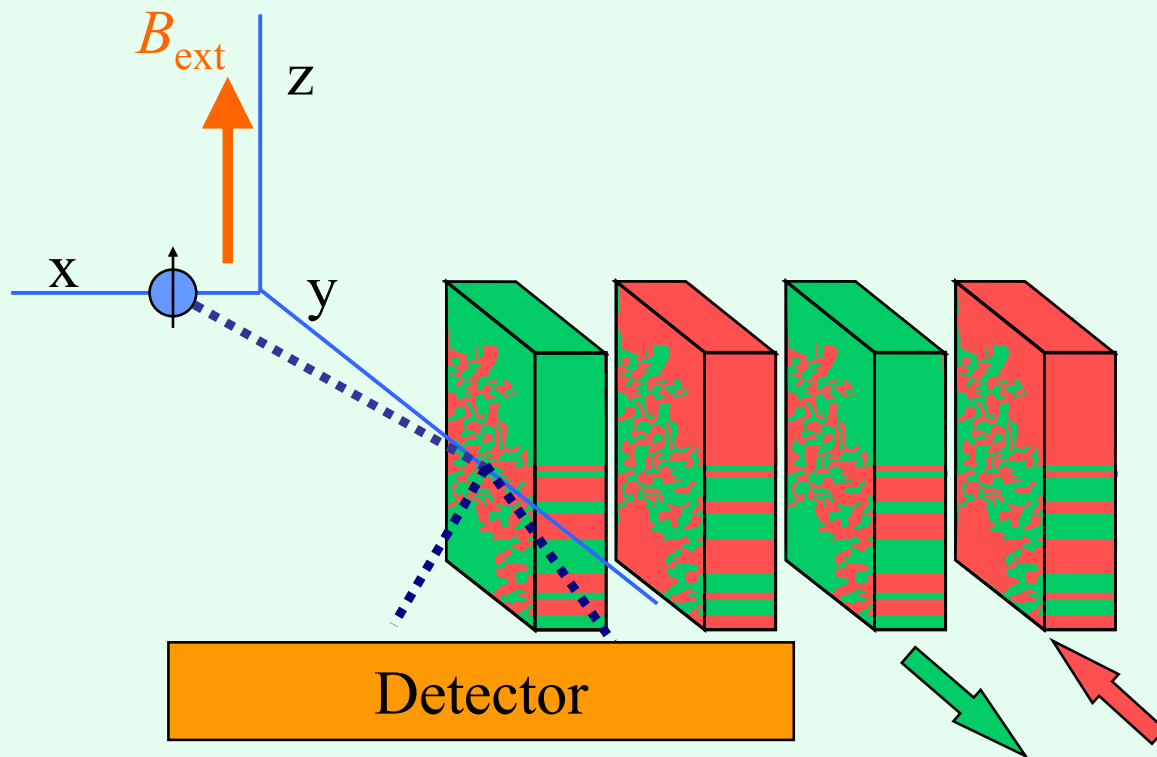
+ for neutron spin parallel to magnetisation

- for neutron spin antiparallel to magnetisation

for neutron spin perpendicular to magnetisation:
spin-flip scattering!

Neutron reflectometry

AF coupling: magnetic doubling of the 'unit cell', appearance of half order reflection peaks



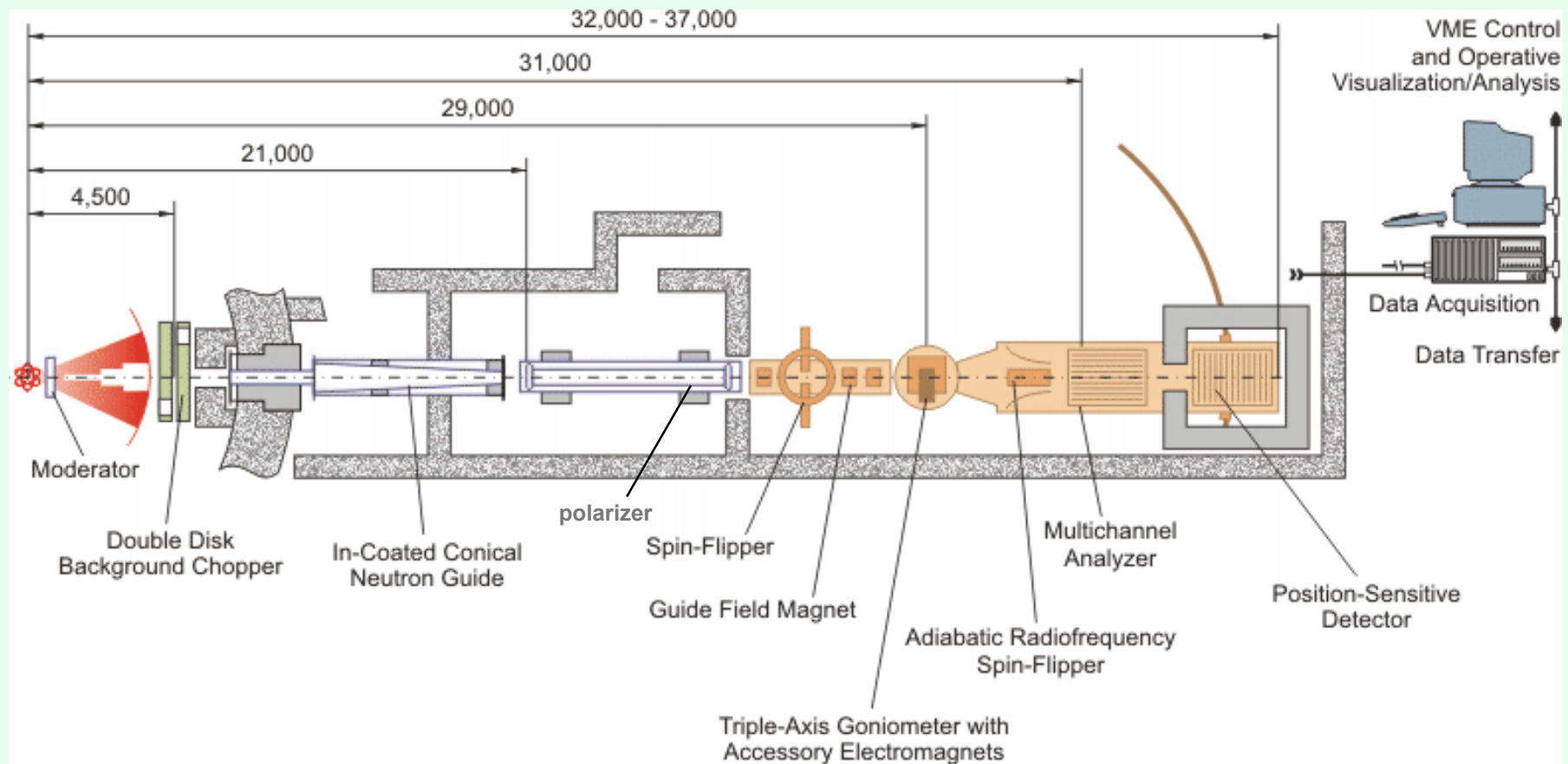
The off-specular scattering width

- The off-specular (diffuse) scattering width around an **AF** reflection stems **only** from the **magnetic** roughness.
- The diffuse scattering width ΔQ_x at an AF reflection is inversely proportional to the **correlation length** ξ of **M**:

$$\xi = 1/\Delta Q_x$$

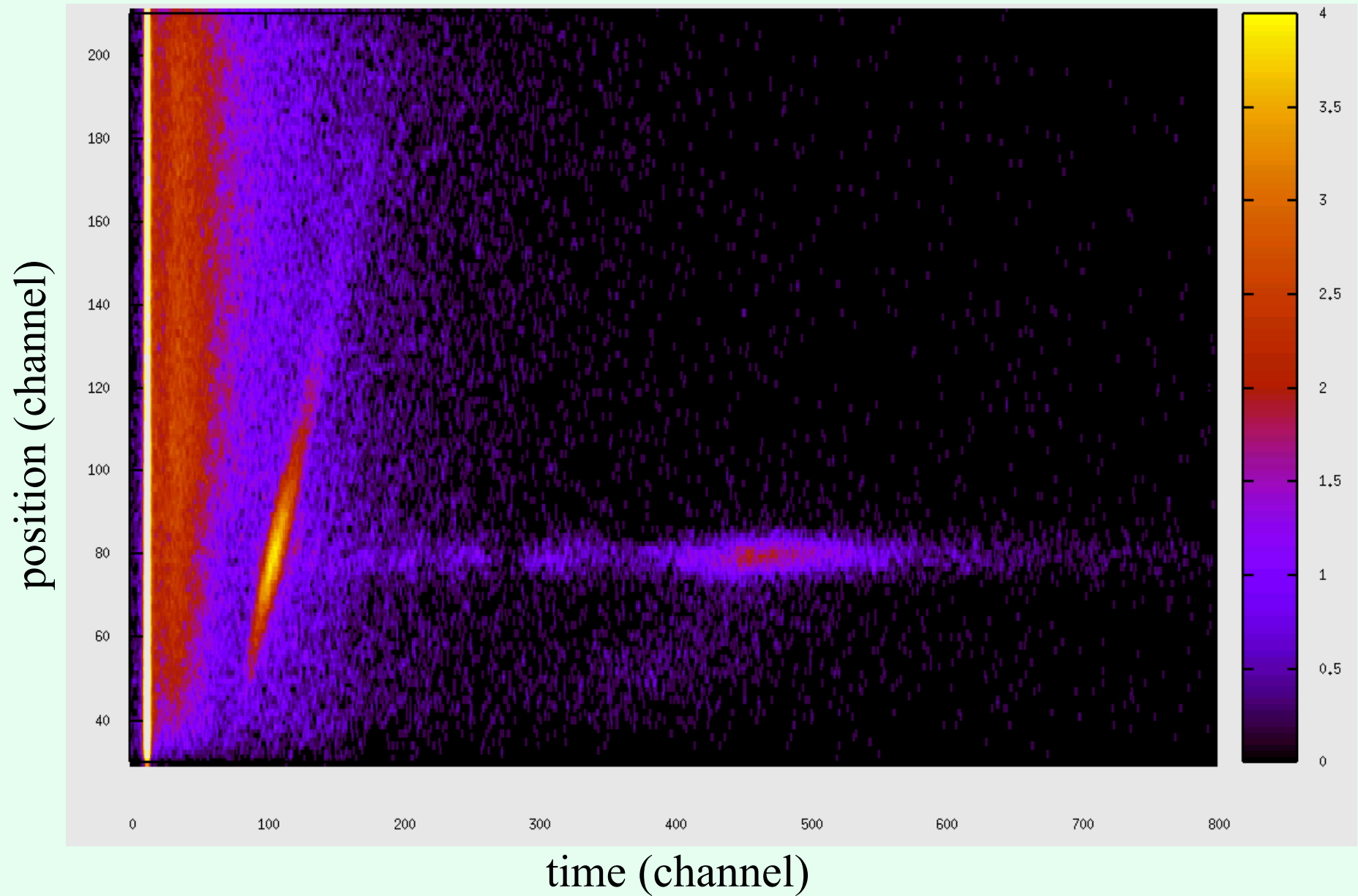
At an **AF reflection**, ξ is the average **domain size!**

Arrangement of the PNR experiments

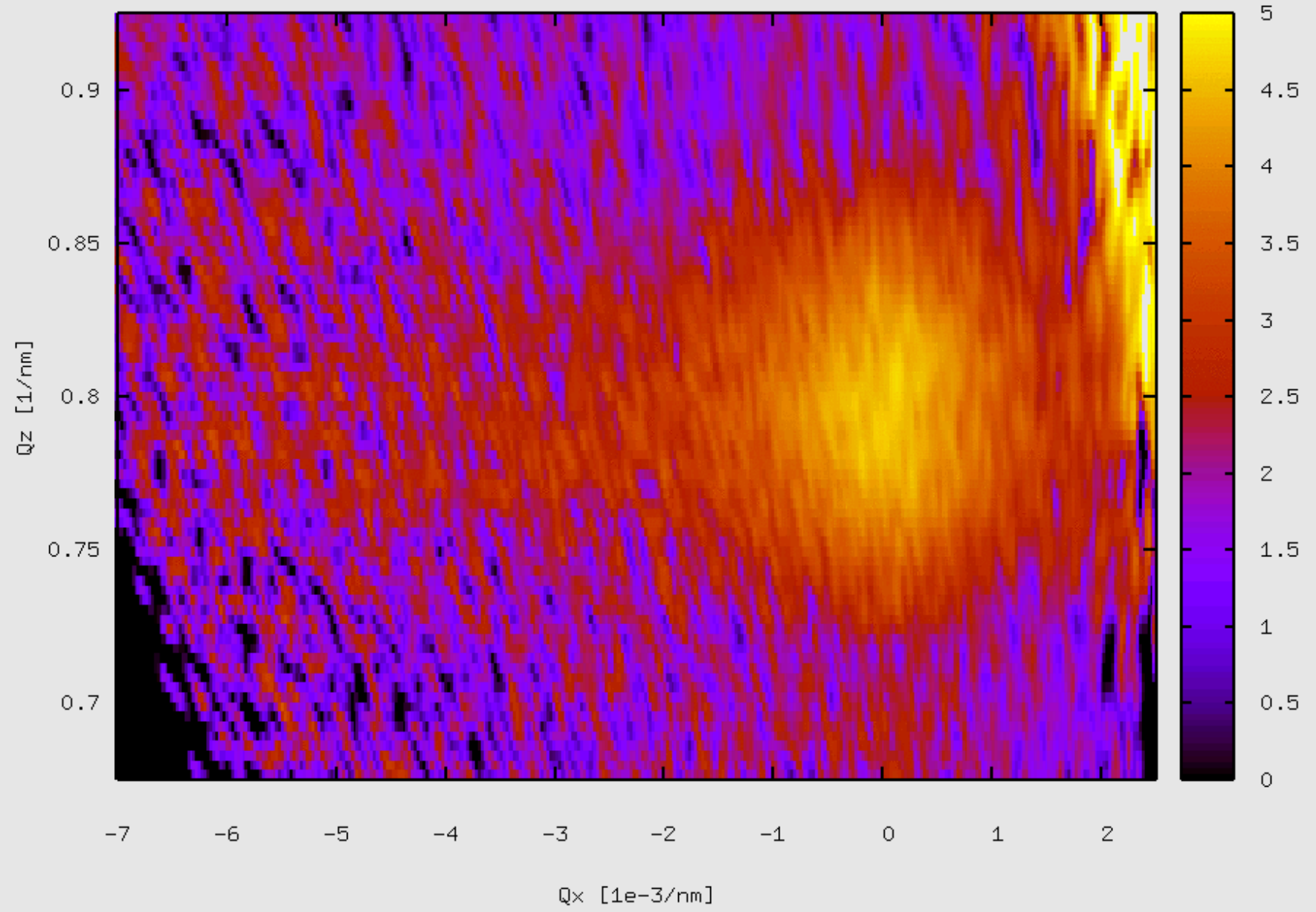


<http://nfdfn.jinr.ru/ibr2.html>

Raw data

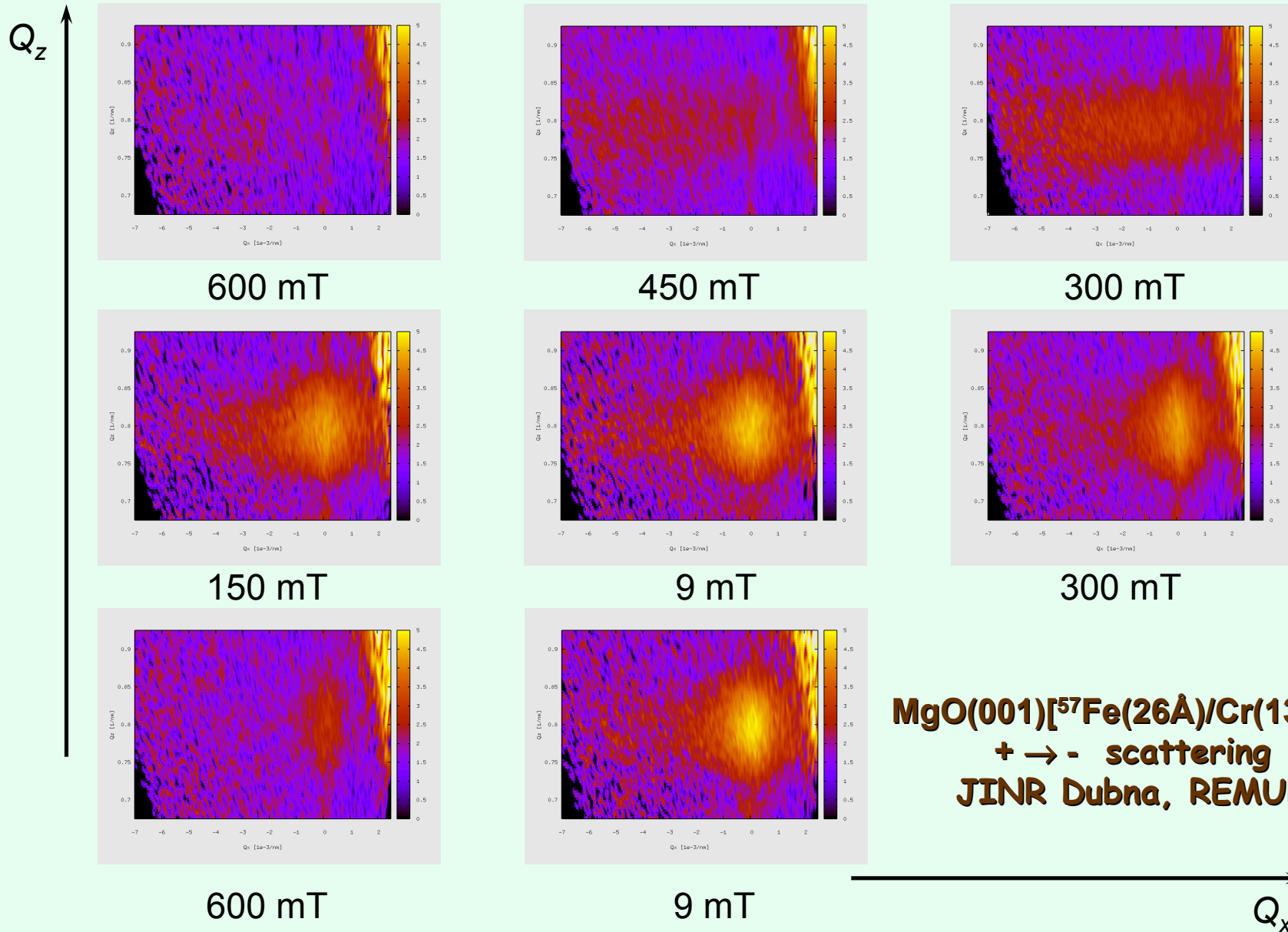


9 mT

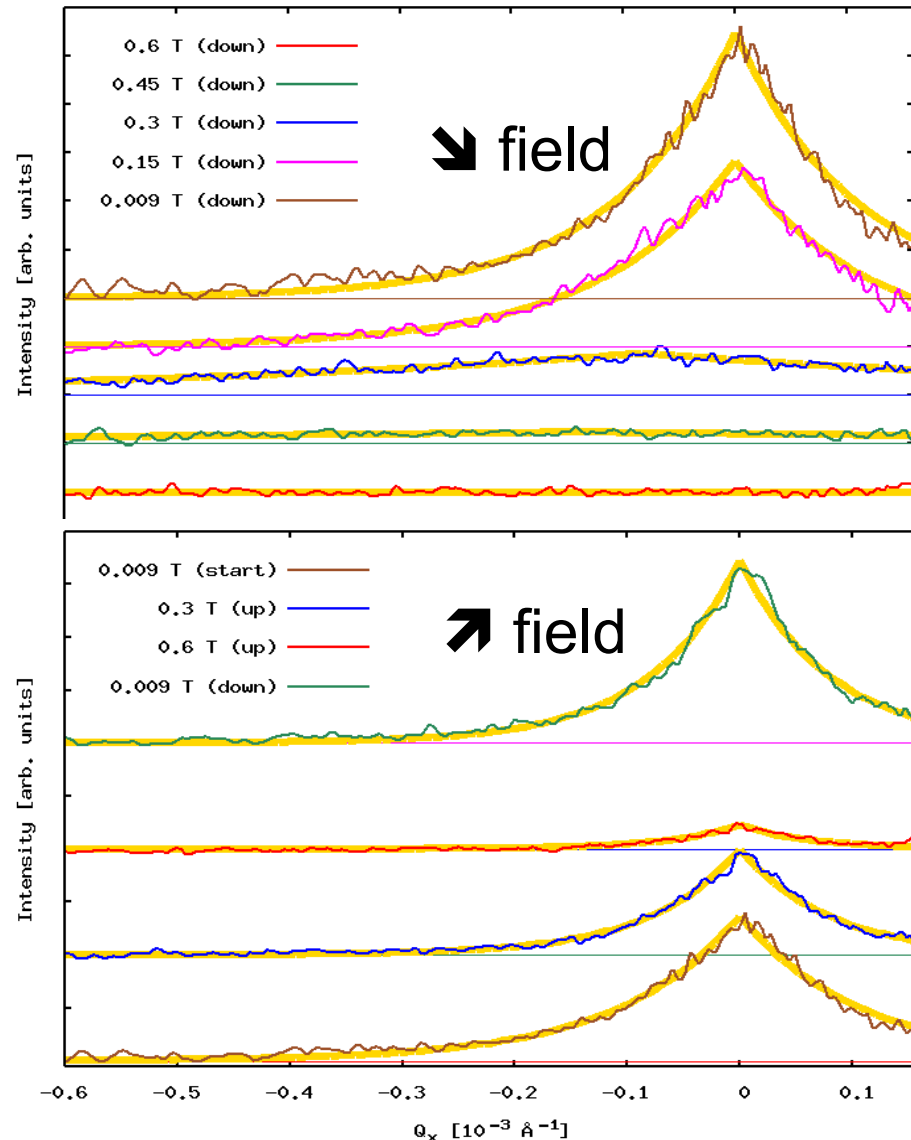


Domain ripening as seen
by PNR

Domain ripening: off-specular PNR, easy axis



Domain ripening: PNR (Q_z -integrated)



Correlation length:

$$\xi = 1/\Delta Q_x$$

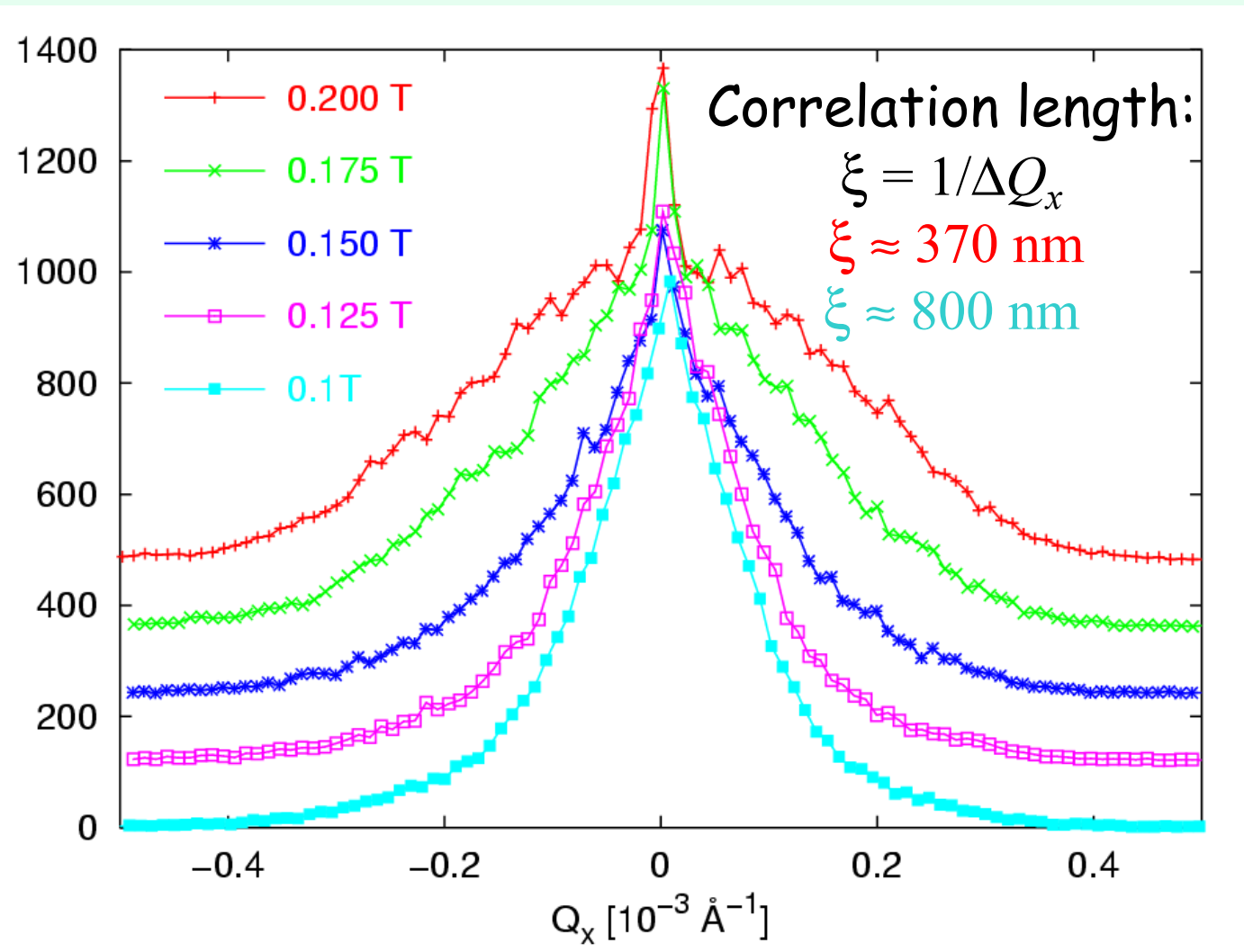
$$\xi \approx 370 \text{ nm}$$

$$\xi \approx 800 \text{ nm}$$

→ Domain ripening is an irreversible process: the domain size does not appear to change on later increasing or decreasing the field.

Domain ripening: off-specular SMR

MgO(001)[⁵⁷Fe(26Å)/Cr(13Å)]₂₀
2 θ @ AF reflection, hard axis



ESRF
ID18

Conclusions

- The native domains **do not change their shape and size** from saturation down to 200 mT (evidence from SMR measurements).
- The native domain size is 370 nm.
- Between 300 and remanence, **ripening** of the domains takes place (SMR evidence: 200-100 mT). The domain size **increases** to 800 nm.
- The domain ripening is **irreversible**, as long as the domain structure is not erased by saturating the multilayer.